

## Monolithic General-Purpose CMOS Analog Switch

### Features

- $\pm 15\text{-V}$  Input Range
- On-Resistance:  $<50\ \Omega$
- Break-Before-Make Switching
- TTL and CMOS Compatible

### Benefits

- Improved Signal Headroom
- Reduced Switching Errors
- No Shorting of Inputs
- Simple Interfacing

### Applications

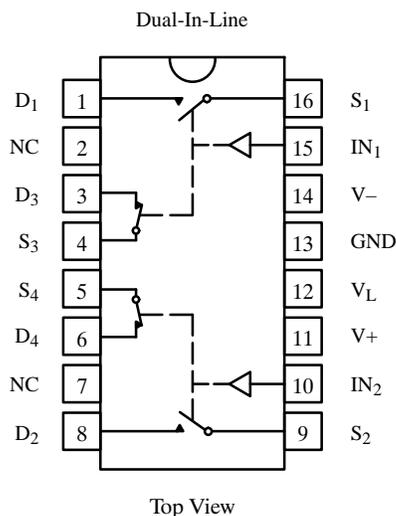
- Audio Switching
- Instrumentation
- Battery Powered Systems

### Description

The DG5043 solid state analog switch is recommended for general purpose applications in instrumentation, and process control. Built on the Siliconix PLUS-40 high voltage CMOS process, this device provides ease-of-use and performance advantages to the system designer. Key performance features of the DG5043 are 1- $\mu\text{s}$  switching,

low power supply requirements, and break-before-make switching. Each switch conducts equally well in either direction, when on, and blocks up to 30 V peak-to-peak when off. Off leakage current is 1-nA maximum. An epitaxial layer prevents latch up. For new designs, DG403 is recommended.

### Functional Block Diagram and Pin Configuration



Truth Table

Logic	SW <sub>1</sub> , SW <sub>2</sub>	SW <sub>3</sub> , SW <sub>4</sub>
0	OFF	ON
1	ON	OFF

Logic "0" =  $\leq 0.8\text{ V}$   
Logic "1" =  $\geq 2\text{ V}$

Ordering Information

Temp Range	Package	Part Number
0 to 70°C	16-Pin Plastic DIP	DG5043CJ

Updates to this data sheet may be obtained via facsimile by calling Siliconix FaxBack, 1-408-970-5600. Please request FaxBack document #70059.

## Absolute Maximum Ratings

V+ to V-	44 V
GND to V-	25 V
V <sub>L</sub>	(GND - 0.3 V) to 44 V
Digital Inputs <sup>a</sup> V <sub>S</sub> , V <sub>D</sub>	(V-) -2 V to (V+ plus 2 V) or 30 mA, whichever occurs first
Current (Any Terminal) Continuous	30 mA
Current, S or D (Pulsed 1 ms 10% duty)	100 mA
Storage Temperature	-65 to 125°C

Power Dissipation (Package) <sup>b</sup>	
16-Pin Plastic DIP <sup>c</sup>	470 mW

Notes:

- Signals on S<sub>X</sub>, D<sub>X</sub>, or IN<sub>X</sub> exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC Board.
- Derate 6 mW/°C above 75°C

## Specifications

Parameter	Symbol	Test Conditions Unless Otherwise Specified  V+ = 15 V, V- = -15 V V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2 V, 0.8 V <sup>e</sup>	Temp <sup>a</sup>	C Suffix 0 to 70°C			Unit
				Min <sup>c</sup>	Typ <sup>b</sup>	Max <sup>c</sup>	
<b>Analog Switch</b>							
Analog Signal Range <sup>d</sup>	VANALOG		Full	-15		15	V
Drain-Source On-Resistance	r <sub>DS(on)</sub>	I <sub>S</sub> = -10 mA, V <sub>D</sub> = ± 10 V	Room Full			50 75	Ω
Switch Off Leakage Current	I <sub>S(off)</sub>	V <sub>S</sub> = V <sub>D</sub> = 14 V	Room Full	-1 -100		1 100	nA
		V <sub>S</sub> = V <sub>D</sub> = -14 V	Room Full	-1 -100		1 100	
Channel On Leakage Current	I <sub>D(on)</sub>	V <sub>S</sub> = V <sub>D</sub> = 14 V	Room Full			2 200	
		V <sub>S</sub> = V <sub>D</sub> = -14 V	Room Full	-2 -200			
<b>Digital Control</b>							
Input Current with V <sub>IN</sub> Low	I <sub>IL</sub>	V <sub>IN</sub> Under Test = 0.8 V	Full	-1		1	μA
Input Current with V <sub>IN</sub> High	I <sub>IH</sub>	V <sub>IN</sub> Under Test = 2 V	Full	-1		1	
<b>Dynamic Characteristics</b>							
Turn-On Time	t <sub>ON</sub>	V <sub>S</sub> = ± 10 V, R <sub>L</sub> = 1 kΩ, C <sub>L</sub> = 35 pF See Figure 1	Room			1200	ns
Turn-Off Time	t <sub>OFF</sub>		Room			700	
Charge Injection <sup>d</sup>	Q	C <sub>L</sub> = 10 nF, V <sub>gen</sub> = 0 V, R <sub>gen</sub> = 0 Ω	Room		30		pC
Off Isolation <sup>d</sup>	OIRR	R <sub>L</sub> = 75 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz	Room		75		dB
Crosstalk (Channel-to-Channel) <sup>d</sup>	X <sub>TALK</sub>	R <sub>L</sub> = 75 Ω, V <sub>S</sub> = 2 V <sub>P-P</sub> , f = 1 MHz	Room		89		
Source Off Capacitance	C <sub>S(off)</sub>	V <sub>D</sub> = V <sub>S</sub> = 0 V, f = 1 MHz	Room		15		pF
Drain Off Capacitance <sup>d</sup>	C <sub>D(off)</sub>		Room		17		
Channel On Capacitance <sup>d</sup>	C <sub>D(on)</sub>		Room		45		

## Specifications

Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 15\text{ V}, V_- = -15\text{ V}$ $V_L = 5\text{ V}, V_{IN} = 2\text{ V}, 0.8\text{ V}^e$	Temp <sup>a</sup>	C Suffix 0 to 70°C			Unit
				Min <sup>c</sup>	Typ <sup>b</sup>	Max <sup>c</sup>	
<b>Power Supplies</b>							
Positive Supply Current	$I_+$	$V_{IN} = 0$ or $2.4\text{ V}$	Full			300	$\mu\text{A}$
Negative Supply Current	$I_-$		Full	-300			
Logic Supply Current	$I_L$		Full			300	
Ground Current	$I_{GND}$	Full	-300				

Notes:

- Room = 25°C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- $V_{IN}$  = input voltage to perform proper function.

## Test Circuits

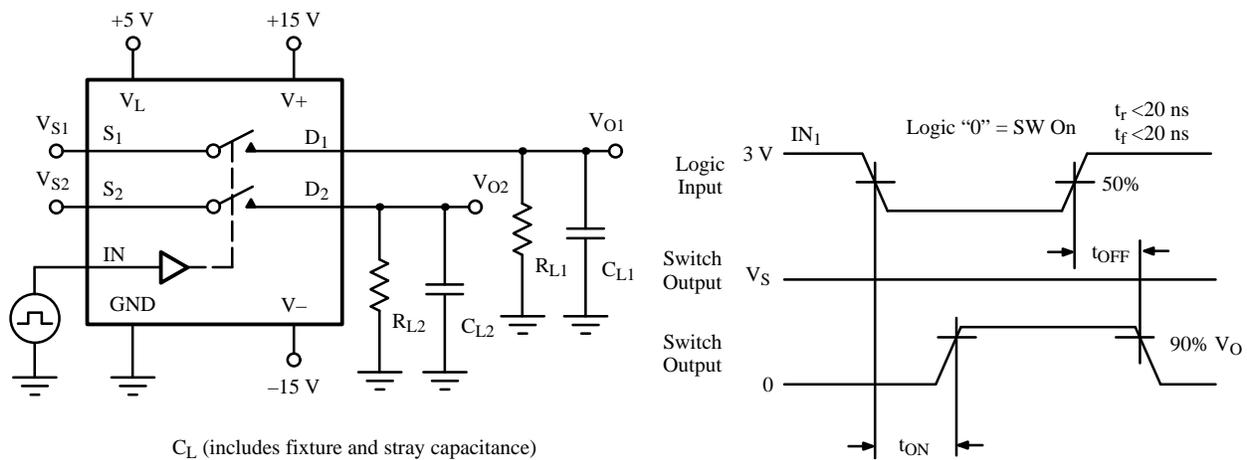


Figure 1. Switching Time

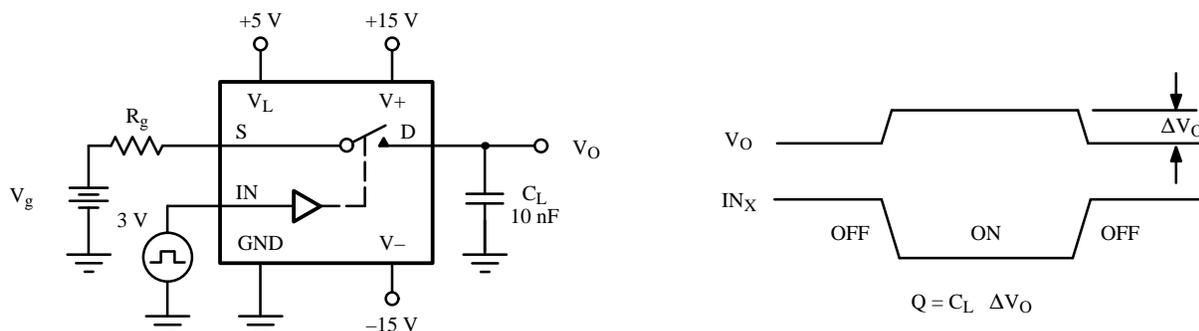


Figure 2. Charge Injection